

## 2SA1405/2SC3599

# Ultrahigh-Difinition CRT Display Video Output Applications

## **Applications**

- · Ultrahigh-definition CRT display.
- · Video output.
- · Color TV chroma output.
- · Wide-band amp.

#### **Features**

- · High  $f_T$ :  $f_T$  typ=500MHz.
- · High breakdown voltage : V<sub>CEO</sub>≥120V.
- · Small reverse transfer capacitance and excellent high-frequnecy characteristic
  - : C<sub>re</sub>=2.5pF (NPN), 3.8pF (PNP).
- · Complementary pair with the 2SA1405/2SC3599.
- · Adoption of FBET process.

(): 2SA1405

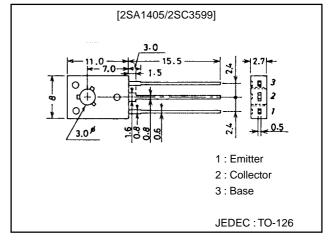
## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

## **Package Dimensions**

unit:mm

2009B

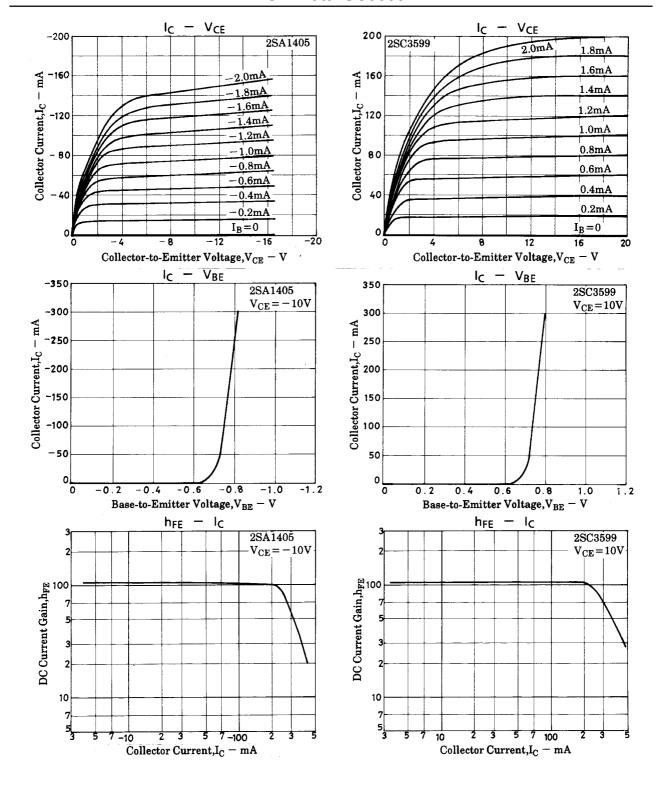


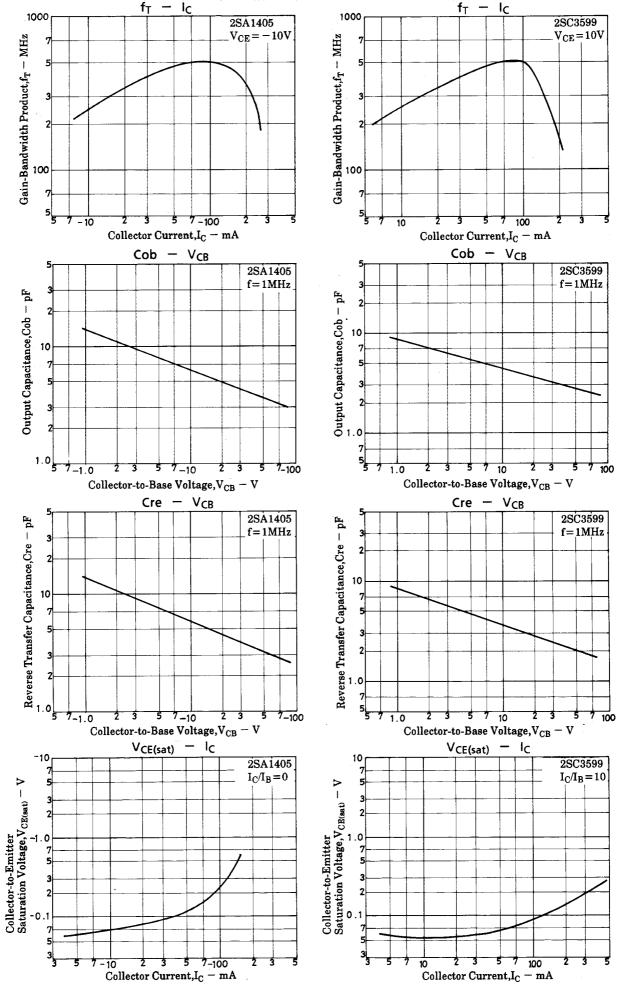
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)120	V
Collector-to-Emitter Voltage	VCEO		(-)120	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)4	V
Collector Current	IC		(-)300	mA
Collector Current (Pulse)	I <sub>CP</sub>		(-)600	mA
Collector Dissipation	PC		1.2	W
		Tc=25°C	8	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

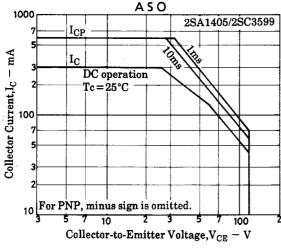
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	UIIIL
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)80V, I <sub>E</sub> =0			(–)0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)2V, I <sub>C</sub> =0			(–)1.0	μΑ
DC Current Gain	h <sub>FE</sub> 1	V <sub>CB</sub> =(-)10V, I <sub>C</sub> =(-)50mA	40*		320*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =250mA	20			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		500		MHz
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)70mA, I <sub>B</sub> =(-)7mA			0.6	V
					(–)0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)70mA, I <sub>B</sub> =(-)7mA			(–)1.0	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10μΑ, I <sub>E</sub> =0	(–)120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=(-)1mA, R <sub>BE</sub> =∞	(–)120			V
Emitter-to-Base Breakdown Votage	V(BR)EBO	I <sub>E</sub> =(-)100μA, I <sub>C</sub> =0	(-)4			V
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.9		pF
				(4.3)		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.5		pF
				(3.8)		pF

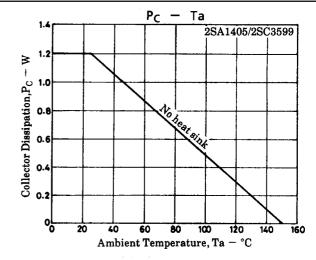
<sup>\* :</sup> The 2SA1405/2SC3599 are classified by 50mA h<sub>FE</sub> as follows :

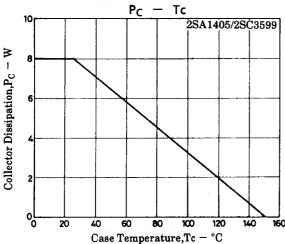




### 2SA1405/2SC3599







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